QOUND

February 17, 2010

RFMD(R) Expands Industry-Leading 3G Product Portfolio With TD-SCDMA Power Amplifier

RFMD Has Secured Design Wins Across Leading TD-SCDMA Reference Designs And Handset Manufacturers

BARCELONA, Spain, Feb 17, 2010 /PRNewswire via COMTEX News Network/ -- RF Micro Devices, Inc. (Nasdaq GS: RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced it has expanded its industry-leading 3G front end product portfolio with the RF7234, RFMD's second-generation TD-SCDMA power amplifier (PA). The dual-mode RF7234 (TD-SCDMA and WCDMA band 1) follows RFMD's first-generation TD-SCDMA PA, the RF3266, which has secured multiple design wins across leading TD-SCDMA reference designs and is forecast to support multiple top-tier handset manufacturers headquartered in Asia and Europe.

Both the RF7234 and RF3266 deliver superior performance at peak power conditions and ample margin across spectral emissions mask requirements - meeting or exceeding the critical performance metrics of today's TD-SCDMA handsets. Accordingly, RFMD is supporting multiple TD-SCDMA reference designs, including MediaTek and T3G, and RFMD expects robust growth in TD-SCDMA handsets in calendar 2010, driven by Samsung, ZTE, BYD, LG and other leading handset manufacturers.

Eric Creviston, president of RFMD's Cellular Products Group (CPG), said, "RFMD is introducing a record number of new cellular components this year in support of our customers' new handset builds. We are particularly focused on expanding our leadership in 3G with a broad product family that is cost- and feature set-optimized for this rapidly emerging, high-growth category. In TD-SCDMA, we are forecasting strong customer adoption of our RF3266 and RF7234, and we expect robust growth in TD-SCDMA devices in calendar 2010."

The RF7234 and RF3266 expand an industry-leading 3G product portfolio that accommodates all major RF architectures, including existing mode-specific/band-specific and mode-specific/multi-band architectures as well as emerging multimode/multi-band, converged architectures. RFMD's innovative 3G products also include a broad range of GSM/GPRS and EDGE power amplifier-based and switch-based components optimized for 3G mobile internet devices, providing a comprehensive RF product portfolio covering the entire cellular front end.

RFMD's product portfolio is on display at the 2010 Mobile World Congress in Barcelona, Spain, February 15 to February 18.

Samples And Availability

Samples of the RF3266 and RF7234 are available immediately. For pricing information, please contact your local RFMD sales representative or visit <u>www.rfmd.com/purchase</u>.

About RFMD

RF Micro Devices, Inc. (Nasdaq: RFMD) is a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at <u>www.rfmd.com</u>.

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and

performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements. other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, variability in operating results, the rate of growth and development of wireless markets, risks associated with the reduced investment in our wireless systems business, our ability to execute on our plans to consolidate or relocate manufacturing operations, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication facilities, molecular beam epitaxy facility, assembly facility and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to bring new products to market, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on a limited number of customers, dependence on gallium arsenide (GaAs) for the majority of our products, and dependence on third parties. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

RF MICRO DEVICES(R) and RFMD(R) are trademarks of RFMD, LLC. All other trade names, trademarks and registered trademarks are the property of their respective owners.

SOURCE RF Micro Devices, Inc.

Copyright (C) 2010 PR Newswire. All rights reserved